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SMCJ5V0(C)A - SMCJ170(C)A 1500 Watt Transient Voltage Suppressors

Features

- · Glass-Passivated Junction
- 1500 W Peak Pulse Power Capability on 10/1000 μs Waveform.
- Excellent Clamping Capability
- · Low-Incremental Surge Resistance
- Fast Response Time: Typically Less than 1.0 ps from 0 V to BV for Unidirectional and 5.0 ns for Bidirectional
- Typical I_R Less than 1.0 μA Above 10 V
- UL Certificate #E258596
- · UL94V-0 Flammability Classification
- Devices for Bipolar Applications
- · Bidirectional Types Use CA Suffix
- Electrical Characteristics Apply in Both Directions



SMC/DO-214AB

COLOR BAND DENOTES CATHODE ON UNIDIRECTIONAL DEVICES ONLY. NO COLOR BAND ON BIDIRECTIONAL DEVICES

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^{\circ}\text{C}$ unless otherwise noted.

Symbol	Parameter	Value	Unit
P _{PPM}	Peak Pulse Power Dissipation on 10/1000 μs Waveform	1500	W C
I _{PPM}	Peak Pulse Current on 10/1000 μs Waveform	See table	A
I _{FSM}	Non-Repetitive Peak Forward Surge Current Superimposed on Rated Load (JEDEC Method) ⁽¹⁾	200	MOA
T _{STG}	Storage Temperature Range	-55 to 150	°C
T _{,1}	Operating Junction Temperature	150	°C

Note

1. Measured on 8.3 ms single half-sine wave or equivalent square wave: duty cycle = 4 pulses per minute maximum.

Electrical Characteristics

Values are at $T_A = 25$ °C unless otherwise noted.

Uni-Directional Bi-Directional (C)	Part Marking ⁽²⁾	Reverse Stand-Off Voltage V _{RWM} (V)	Breakdown Voltage V _{BR} (V)		Test Current I _T (mA)	Clamping Voltage at I _{PPM} V _C (V)	Peak Pulse Current I _{PPM} (A)	Reverse Leakage at V _{RWM} I _R (μA) ⁽³⁾
Device			Min. Max.					
SMCJ5V0(C)A	GDE	5.0	6.40	7.00	10	9.2	163.0	1000
SMCJ6V0(C)A	GDG	6.0	6.67	7.37	10	10.3	145.6	1000
SMCJ6V5(C)A	GDK	6.5	7.22	7.98	10	11.2	133.9	500
SMCJ7V0(C)A	GDM	7.0	7.78	8.60	10	12.0	125.0	200
SMCJ7V5(C)A	GDP	7.5	8.33	9.21	1	12.9	116.3	100
SMCJ8V0(C)A	GDR	8.0	8.89	9.83	1	13.6	110.3	50
SMCJ8V5(C)A	GDT	8.5	9.44	10.4	1	14.4	104.2	20
SMCJ9V0(C)A	GDV	9.0	10.0	11.1	1,111	15.4	97.4	10
SMCJ10(C)A	GDX	10	11.1	12.3	1	17.0	88.2	5
SMCJ11(C)A	GDZ	.11	12.2	13.5	1	18.2	82.4	5
SMCJ12(C)A	GEE	12	13.3	14.7	1	19.9	75.3	5
SMCJ13(C)A	GEG	13	14.4	15.9	1	21.5	69.8	5
SMCJ14(C)A	GEK	14	15.6	17.2	1	23.2	64.7	5
SMCJ15(C)A	GEM	15	16.7	18.5	v 1	24.4	61.5	5
SMCJ16(C)A	GEP	16	17.8	19.7	1	26.0	57.7	5
SMCJ17(C)A	GER	17	18.9	20.9	1	27.6	54.3	5
SMCJ18(C)A	GET	18	20.0	22.1	(11)	29.2	51.4	5
SMCJ20(C)A	GEV	20	22.2	24.5	1	32.4	46.3	5
SMCJ22(C)A	GEX	22	24.4	26.9	100	35.5	42.3	5
SMCJ24(C)A	GEZ	24	26.7	29.5	1	38.9	38.6	5
SMCJ26(C)A	GFE	26	28.9	31.9	1	42.1	35.6	5
SMCJ28(C)A	GFG	28	31.1	34.4	1	45.4	33.0	5
SMCJ30(C)A	GFK	30	33.3	36.8	1.1	48.4	31.0	5
SMCJ33(C)A	GFM	33	36.7	40.6	CQ.	53.3	28.1	5
SMCJ36(C)A	GFP	36	40.0	44.2	~ COM	58.1	25.8	5
SMCJ40(C)A	GFR	40	44.4	49.1	101	64.5	23.3	5
SMCJ43(C)A	GFT	43	47.8	52.8	1011	69.4	21.6	5
SMCJ45(C)A	GFV	45	50.0	55.3	001	72.7	20.6	5
SMCJ48(C)A	GFX	48	53.3	58.9	17.C	77.4	19.4	5
SMCJ51(C)A	GFZ	51	56.7	62.7	1.7	82.4	18.2	5
SMCJ54(C)A	GGE	54	60.0	66.3	N.19	87.1	17.2	5
SMCJ58(C)A	GGG	58	64.4	71.2	W 100 x	93.6	16.0	5
SMCJ60(C)A	GGK	60	66.7	73.7	1,00	96.8	15.5	5
SMCJ64(C)A	GGM	64	71.1	78.6	W 1	103.0	14.6	5
SMCJ70(C)A	GGP	70	77.8	86.0	1	113.0	13.3	5
SMCJ75(C)A	GGR	75	83.3	92.1	111.11	121.0	12.4	5
SMCJ78(C)A	GGT	78	86.7	95.8	1	126.0	11.9	5

Notes:

- 2. Color band denotes cathode on unidirectional devices only. No color band on bidirectional devices.
- 3. For bidirectional parts with V_{RWM} < 10 V, the I_R max limit is doubled.

Electrical Characteristics (Continued)

Uni-Directional Bi-Directional (C)	Part Marking ⁽²⁾	Reverse Stand-Off Voltage V _{RWM} (V)	Breakdown Voltage V _{BR} (V)		Test Current	Clamping Voltage at I _{PPM}	Peak Pulse Current	Reverse Leakage at V _{RWM}
Device			Min.	Max.	I _T (mA)	V _C (V)	I _{PPM} (A)	I _R (μΑ) ⁽³⁾
SMCJ85(C)A	GGV	85	94.4	104.0	AV1.100	137.0	10.9	5
SMCJ90(C)A	GGX	90	100.0	111.0	1,10	146.0	10.3	5
SMCJ100(C)A	GGZ	100	111.0	123.0	1	162.0	9.3	5
SMCJ110(C)A	GHE	110	122.0	135.0	111	177.0	8.5	5
SMCJ120(C)A	GHG	120	133.0	147.0	1	193.0	7.8	5
SMCJ130(C)A	GHK	130	144.0	159.0	1	209.0	7.2	5
SMCJ150(C)A	GHM	150	167.0	185.0	1	243.0	6.2	5
SMCJ160(C)A	GHP	160	178.0	197.0	1/1	259.0	5.8	5
SMCJ170(C)A	GHR	170	189.0	209.0	1.1	275.0	5.5	5

Notes:

- 2. Color band denotes cathode on unidirectional devices only. No color band on bidirectional devices.
- 3. For bidirectional parts with V_{RWM} < 10 V, the I_R max limit is doubled.

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Typical Performance Characteristics

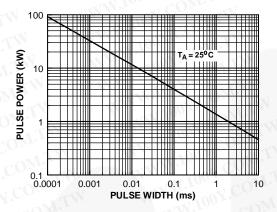


Figure 1. Peak Pulse Power Rating Curve

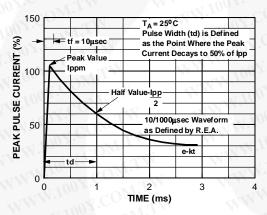


Figure 3. Pulse Waveform

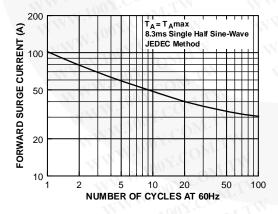


Figure 5. Non-Repetitive Surge Current

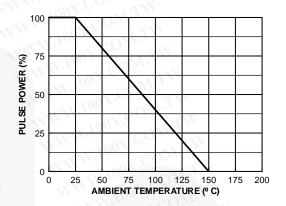


Figure 2. Pulse Derating Curve

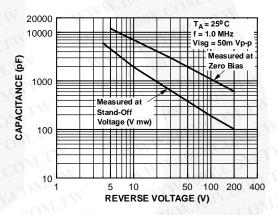


Figure 4. Junction Capacitance

Physical Dimension

DO-214AB (SMC)

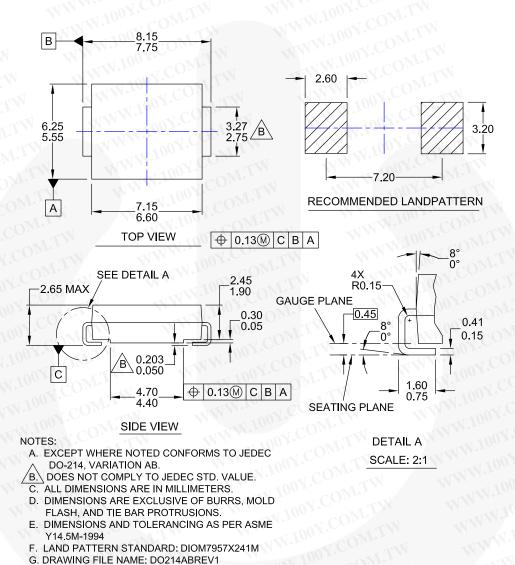


Figure 6. 2-LEAD, SMC, JEDEC DO-214, VARIATION AB (ACTIVE)

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